Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
0.210 inches	
Terminal Length:	
0.500 inches	
Overall Diameter:	
0.230 inches	
Joint Electronic Device Engineering Counc	:il/jedec/case Outline Designation:
To-71	
Component Name And Quantity:	
2 transistor	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.100 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon all transistor	
Voltage Rating In Volts Per Characteristic:	
90.0 collector to base voltage, dc all transisto	or and 90.0 collector to emitter voltage, dc all transistor and 14.0 emitter to base voltage, dc
all transistor	
Current Rating Per Characteristic:	
100.00 milliamperes source cutoff current all	transistor
Power Rating Per Characteristic:	
750.0 milliwatts small-signal input power, con	nmon-collector preset all transistor
Transfer Ratio:	
200.0 static forward current transfer ratio, co	mmon-emitter all transistor
Maximum Operating Tempurature Per Mea	surement Point:
150.0 degrees celsius ambient air	
Special Features:	
All transistor junction pattern arrangement: np	n
Terminal Type And Quantity:	
6 pin	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No 	
Filg:	
A110a0	